

N-Channel 100-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{(BR)DSS} (V)	$r_{DS(on)}(\Omega)$	I _D (A)		
100	0.018 at V _{GS} = 10 V	65 ^a		

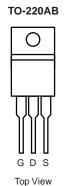
FEATURES

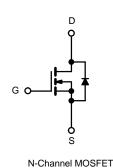
- DT-Trench Power MOSFET
- 175 °C Junction Temperature
- · Low Thermal Resistance Package
- 100 % R_g Tested



APPLICATIONS

· Isolated DC/DC Converters





ABSOLUTE MAXIMUM RATINGS $T_C = 25$ °C, unless otherwise noted Parameter Symbol Limit Unit Drain-Source Voltage V_{DS} 100 ٧ ± 20 Gate-Source Voltage V_{GS} T_C = 25 °C 65^a Continuous Drain Current (T_J = 175 °C) I_D T_C = 125 °C 37^a Α **Pulsed Drain Current** 195 I_{DM} 35 Avalanche Current I_{AS} L = 0.1 mH E_{AS} 61 Single Pulse Avalanche Energy^b mJ $T_C = 25$ °C 375^c Maximum Power Dissipation^b P_D W $T_A = 25 \, ^{\circ}C^d$ 3.75 Operating Junction and Storage Temperature Range T_J , T_{stg} - 55 to 175 °С

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Limit	Unit	
Junction-to-Ambient	PCB Mount (TO-263) ^d	R _{thJA}	40	°C/W	
Junction-to-Case (Drain)		R _{thJC}	0.4	C/VV	

Notes:

- a. Package limited.
- b. Duty cycle \leq 1 %.
- c. See SOA curve for voltage derating.
- d. When Mounted on 1" square PCB (FR-4 material).



Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{(BR)DSS}	$V_{DS} = 0 \text{ V}, I_{D} = 250 \mu\text{A}$	100			4 V	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1		4		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
		$V_{DS} = 80 \text{ V}$, $V_{GS} = 0 \text{ V}$			1	μA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 80 V, V _{GS} = 0 V, T _J = 125 °C			50		
		$V_{DS} = 80 \text{ V} , V_{GS} = 0 \text{ V}, T_{J} = 175 ^{\circ}\text{C}$			250		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	65			Α	
		V _{GS} = 10 V, I _D = 20 A		0.018	0.025	Ω	
Drain-Source On-State Resistance ^a	r _{DS(on)}	V _{GS} = 10 V, I _D = 15 A, T _J = 125 °C		0.021	0.029		
		V _{GS} = 10 V, I _D = 10 A, T _J = 175 °C		0.024	0.033		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 80 V, I _D = 20 A		110		S	
Dynamic ^b							
Input Capacitance	C _{iss}			5100		pF	
Output Capacitance	C _{oss}	$V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$		480			
Reverse Transfer Capacitance	C _{rss}			210			
Total Gate Charge ^c	Q_g			90	130	nC	
Gate-Source Charge ^c	Q_{gs}	$V_{DS} = 80 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$		23			
Gate-Drain Charge ^c	Q_{gd}			34			
Gate Resistance	R_g		0.5	1.7	3.3	Ω	
Turn-On Delay Time ^c	t _{d(on)}			24	35		
Rise Time ^c	t _r	$V_{DD} = 80 \text{ V}, R_{L} = 1.5 \Omega$		220	330	ns	
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong 20 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 2.5 \Omega$		45	70		
Fall Time ^c	t _f			200	300		
Source-Drain Diode Ratings and Ch	aracteristics 7	T _C = 25 °C ^b					
Continuous Current	IS				65	۸	
Pulsed Current	I _{SM}				195	A	
Forward Voltage ^a	V_{SD}	I _F = 20 A, V _{GS} = 0 V		1.0	1.5	V	
Reverse Recovery Time	t _{rr}			130	200	ns	
Peak Reverse Recovery Current	I _{RM(REC)}	I _F = 20 A, di/dt = 100 A/μs		8	12	Α	
Reverse Recovery Charge	Q _{rr}			0.52	1.2	иC	

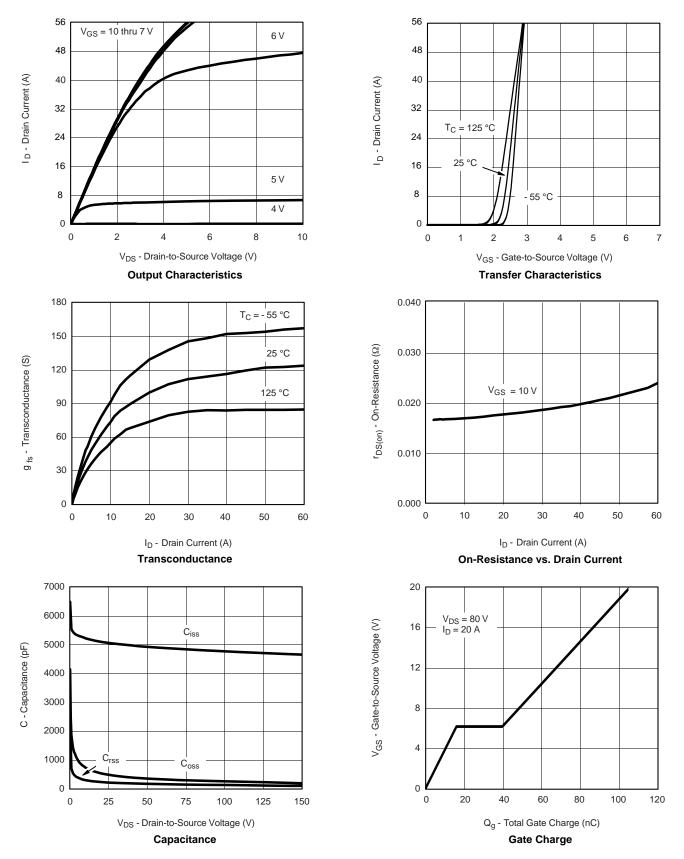
Notes:

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

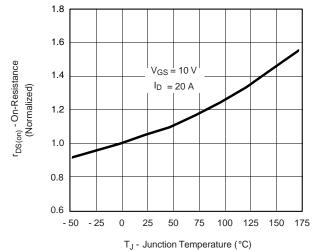


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

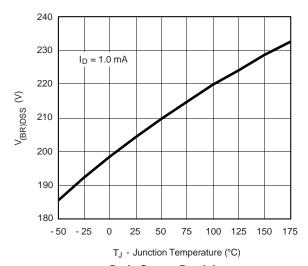




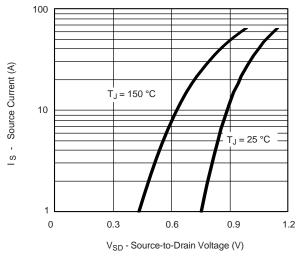
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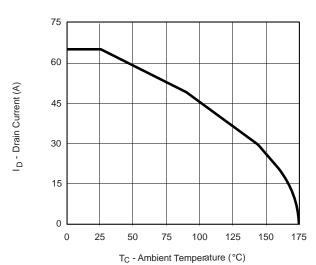
On-Resistance vs. Junction Temperature



Drain Source Breakdown vs. Junction Temperature

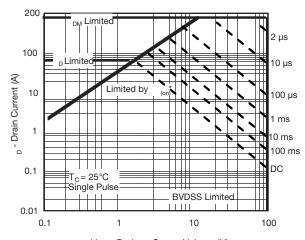


Source-Drain Diode Forward Voltage



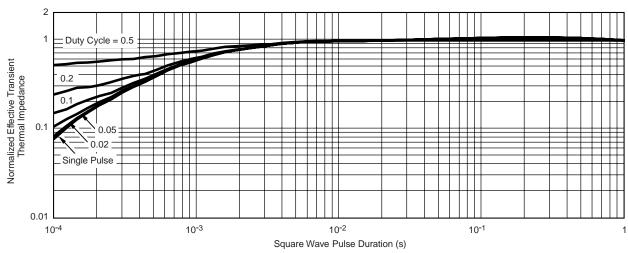
Maximum Avalanche and Drain Current vs. Case Temperature

THERMAL RATINGS



 $\label{eq:VDS} $$V_{DS}$ - Drain-to-SourceVoltage (V) $$^*V_{GS} > minimum\,V_{GS}$ at which $r_{DS(on)}$ is specified$

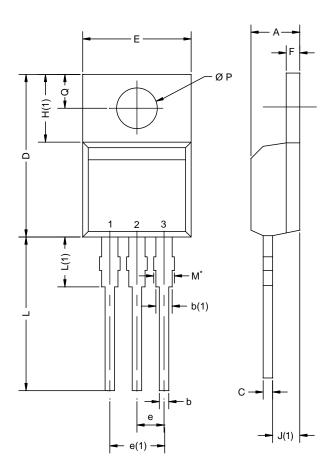
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Case



TO-220AB



	MILLIM	IETERS	INCHES		
DIM.	MIN.	MAX.	MIN.	MAX.	
Α	4.25	4.65	0.167	0.183	
b	0.69	1.01	0.027	0.040	
b(1)	1.20	1.73	0.047	0.068	
С	0.36	0.61	0.014	0.024	
D	14.85	15.49	0.585	0.610	
Е	10.04	10.51	0.395	0.414	
е	2.41	2.67	0.095	0.105	
e(1)	4.88	5.28	0.192	0.208	
F	1.14	1.40	0.045	0.055	
H(1)	6.09	6.48	0.240	0.255	
J(1)	2.41	2.92	0.095	0.115	
L	13.35	14.02	0.526	0.552	
L(1)	3.32	3.82	0.131	0.150	
ØΡ	3.54	3.94	0.139	0.155	
Q	2.60	3.00	0.102	0.118	
ECN: X12-0208-Rev. N, 08-Oct-12 DWG: 5471					

Notes

 $^{^{*}}$ M = 1.32 mm to 1.62 mm (dimension including protrusion) Heatsink hole for HVM





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